

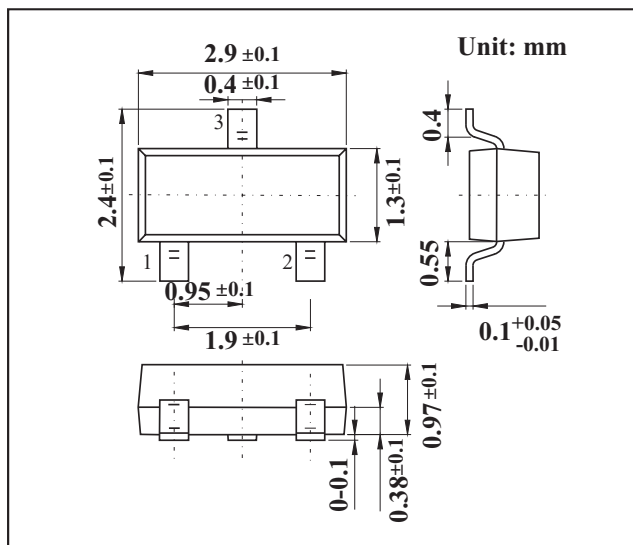
SOT-23 Small Signal Switching Diodes

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed:260 °C/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: SOT-23 molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

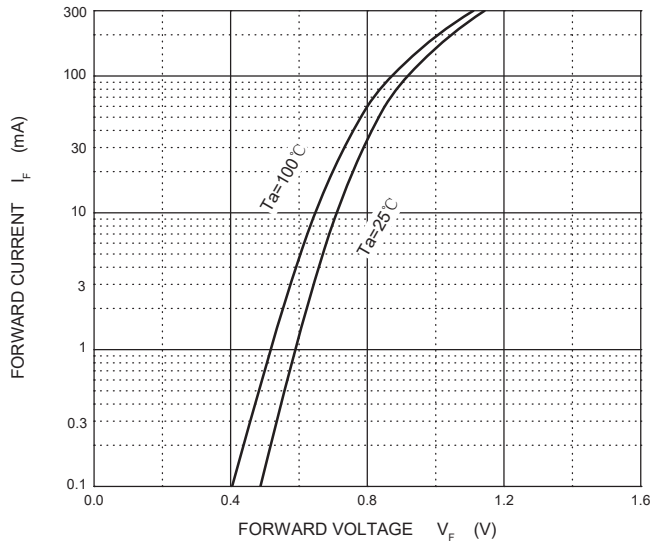
@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
Average Rectified Output Current	I_O	300	mA
Non-Repetitive Peak Forward Surge Current @ $t=8.3ms$	I_{FSM}	2	A
Power Dissipation	P_D	350	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	357	°C/W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{STG}	-55~+150	°C

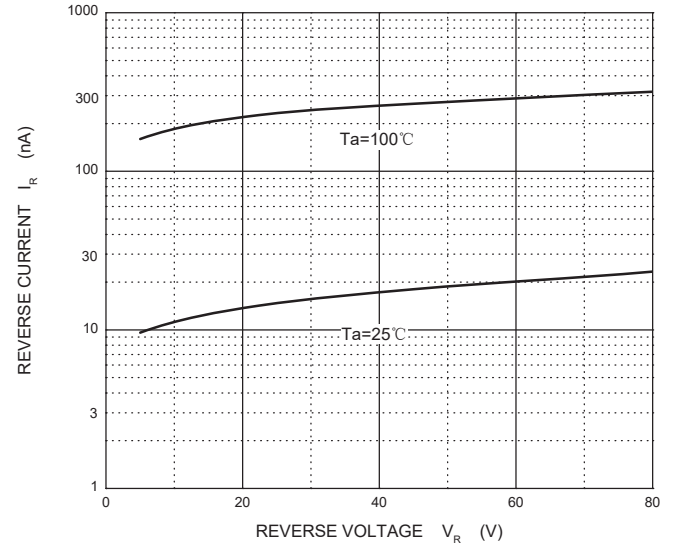
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR)}$	100			V	$I_R=100\mu A$
Forward Voltage	V_{F1}			715	mV	$I_F=1mA$
	V_{F2}			855	mV	$I_F=10mA$
	V_{F3}			1000	mV	$I_F=50mA$
	V_{F4}			1250	mV	$I_F=150mA$
Reverse Current	I_{R1}			1	uA	$V_R=75V$
	I_{R2}			25	nA	$V_R=20V$
Diode Capacitance	C_D			2	pF	$V_R=0, f=1MHz$
Reverse Recovery Time	t_{rr}			4	ns	$I_F=I_R=10mA,$ $I_{rr}=0.1*I_R$

RATINGS AND CHARACTERISTIC CURVES

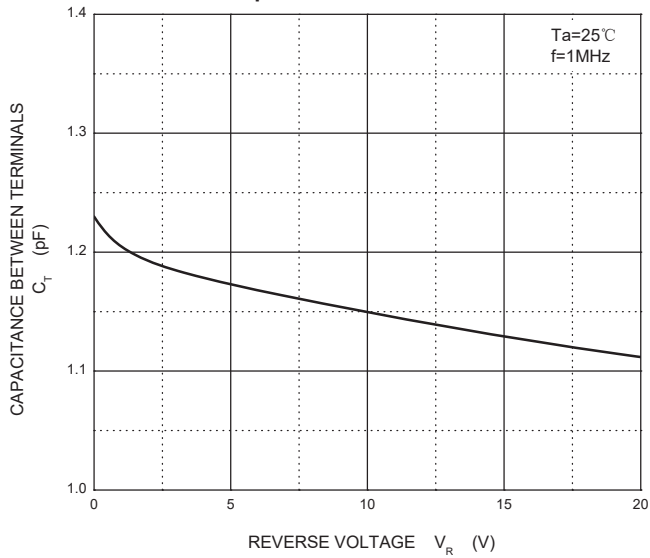
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

